



G2SB20 thru G2SB80

New Product

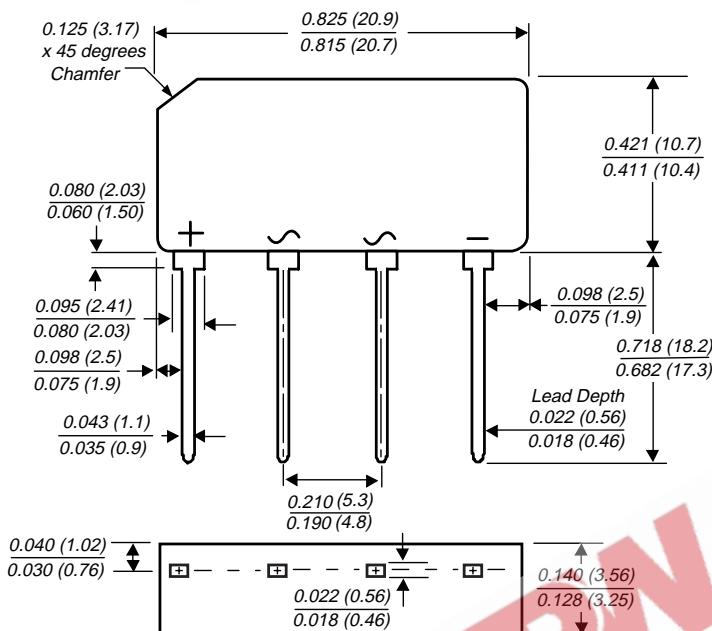
Vishay Semiconductors  
formerly General Semiconductor



## Glass Passivated Single-Phase Bridge Rectifier

Reverse Voltage 200 to 800V  
Forward Current 1.5A

### Case Type GBL



Dimensions in inches and (millimeters)

### Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- This series is UL listed under the Recognized Component Index, file number E54214
- High case dielectric strength
- Ideal for printed circuit boards
- Glass passivated chip junction
- High surge current capability
- High temperature soldering guaranteed: 260°C/10 seconds, 0.375 (9.5mm) lead length, 5lbs. (2.3kg) tension

### Mechanical Data

**Case:** Molded plastic body over passivated junctions

**Terminals:** Plated leads solderable per MIL-STD-750, Method 2026

**Mounting Position:** Any

**Weight:** 0.071 oz., 2.0 g

**Packaging codes/options:**

1/400 EA. per Bulk Tray Stack, 4K/box

### Maximum Ratings & Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

| Parameter   | Symbol                               | G2SB20 | G2SB60      | G2SB80 | Unit               |
|---|--------------------------------------|--------|-------------|--------|--------------------|
| Maximum repetitive peak reverse voltage   | V <sub>RRM</sub>                     | 200    | 600         | 800    | V                  |
| Maximum RMS voltage   | V <sub>RMS</sub>                     | 140    | 420         | 560    | V                  |
| Maximum DC blocking voltage   | V <sub>DC</sub>                      | 200    | 600         | 800    | V                  |
| Maximum average forward rectified output current at T <sub>A</sub> = 25°C             | I <sub>F(AV)</sub>                   |        | 1.5         |        | A                  |
| Peak forward surge current single sine-wave superimposed on rated load (JEDEC Method) | I <sub>FSM</sub>                     |        | 80          |        | A                  |
| Rating for fusing (t<8.3ms)   | I <sup>2</sup> t                     |        | 27          |        | A <sup>2</sup> sec |
| Typical thermal resistance per leg  | R <sub>θJA</sub><br>R <sub>θJL</sub> |        | 40<br>12    |        | °C/W               |
| Operating junction storage and temperature range                                      | T <sub>J</sub> , T <sub>TSG</sub>    |        | -55 to +150 |        | °C                 |

### Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

| Parameter   | Symbol         | G2SB20                  | G2SB60     | G2SB80 | Unit |
|---|----------------|-------------------------|------------|--------|------|
| Maximum instantaneous forward voltage drop per leg at 0.75 A    | V <sub>F</sub> |                         | 1.00       |        | V    |
| Maximum DC reverse current at rated DC blocking voltage per leg | I <sub>R</sub> | TA = 25°C<br>TA = 125°C | 5.0<br>300 |        | μA   |

Note: (1) Unit mounted on P.C.B. with 0.5 x 0.5" (12 x 12mm) copper pads and 0.375" (9.5mm) lead length

# G2SB20 thru G2SB80

Vishay Semiconductors  
formerly General Semiconductor



## Ratings and Characteristic Curves (TA = 25°C unless otherwise noted)

Fig. 1 - Derating Curve Output Rectified Current

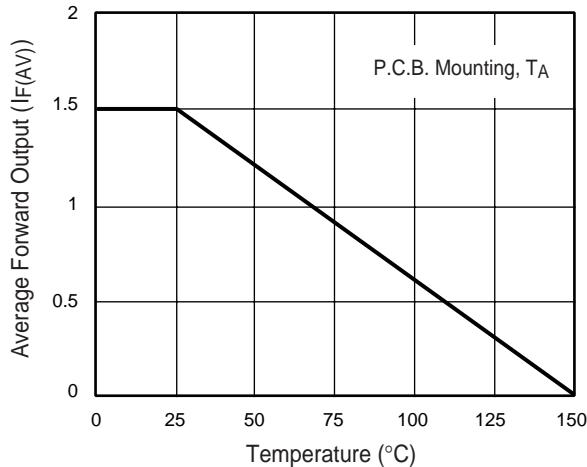


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Leg

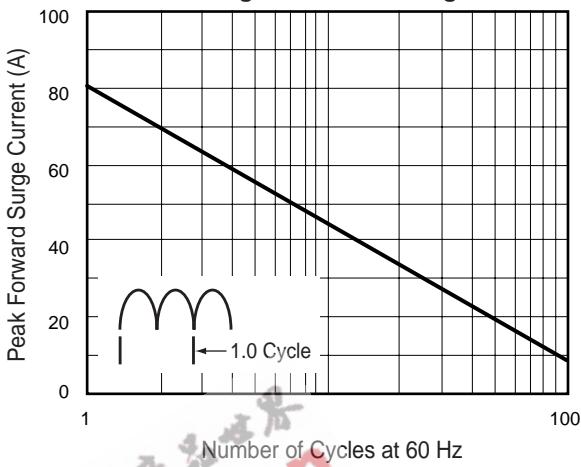


Fig. 3 - Typical Forward Characteristics Per Leg

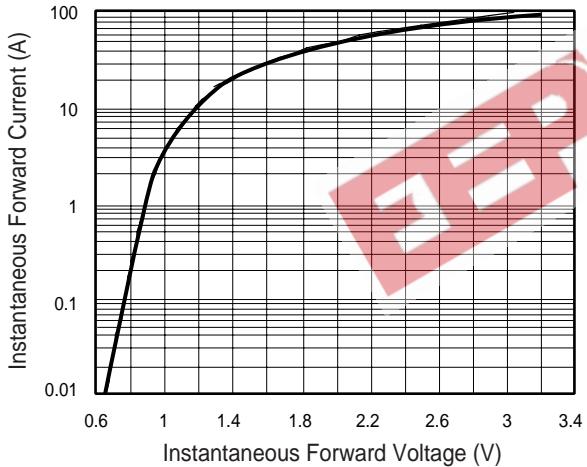


Fig. 4 - Typical Reverse Characteristics Per Leg

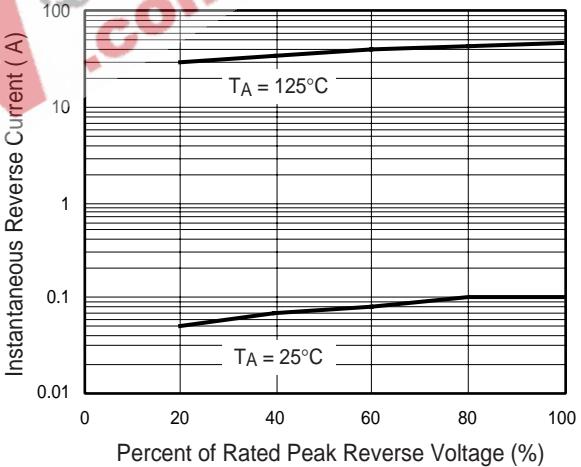


Fig. 5 - Typical Junction Capacitance Per Leg

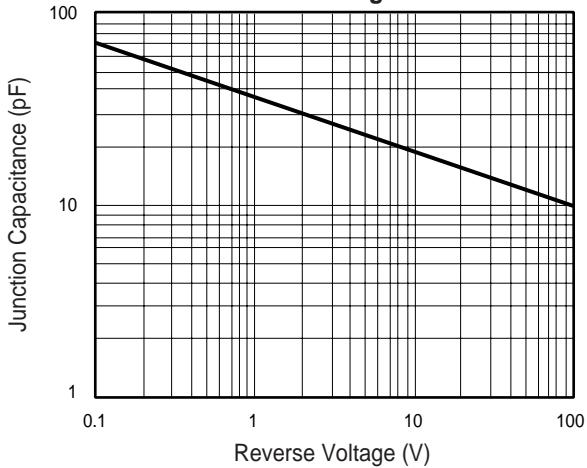


Fig. 6 - Typical Transient Thermal Impedance

